He Retention in Tritides: Importance of **Bubble Location and Spacing Distribution**

Don Cowgill, SNL, Livermore CA USA H and He in Materials Workshop, Albuquerque, Feb 6-7, 2007

- Helium Bubble Linkage and the Transition to Rapid He Release in Pd Tritide (SAND 2006-7779)
 - Effects of the Beta-Induced Reactivity of Er Tritide: Simulation Experiments



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The Bubble Evolution Model



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Model predicts bubble characteristics and He the release spectrum.



The bubble spacing distribution in PdTx was determined by ³He NMR.



The Critical He/M for Bubble Linkage depends on bubble spacing.

- Stress created by neighbors leads toward bubble coalescence.
- Stress-directed bubble growth occurs only for non-symmetric arrays.
 - requires a spacing distribution.





- SD-growth is interrupted by inter-bubble ligament fracture.
 - linkage starts with closely-spaced bubbles.

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Linked Volume Fraction increases with He/M concentration

- Linkage by SD-growth to IB-fracture
 - begins at .32 He/M
 - at .44He/M, incorporates widely-spaced bubbles
 - at .39 He/M, reaches the Critical Volume Fraction for infinite percolation:
- From classical percolation theory in 3d, $V_C = .15$
- In "rapid release", the release rate is 1-2 times the generation rate:

Rel/Gen = (He/M)
$$\frac{dV}{d(He/M)} \approx .4(3) = 1.2$$



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Percolation of surface-connected, linked-bubble clusters gives the *transition* to rapid release.



Early He release depends on the bubble density and defect trapping near surfaces.



However, for Er tritide films, only ³He born within the *top monolayer* escapes!

- He escape depth from [111] oriented ErT₂ films = 1.8 Å (Snow *et al*, 2006)
- What makes He immobile in this layer?
 1) Trapping at Er₂O₃ precipitates?

 requires O/Er ~1 in "hydride"

 2) Trapping within Er(OT)₃ layer?
 3) Er(H,T)₃ near-surface layer?
 - produced by H₂O oxidation
 - He migration blocked by H
- Testing (3) using ErH₂ films, exposed to water vapor in the ALS (LBNL).
 - radiation-enhanced oxidation
 - H-pickup (resistivity, TDS)
 - effect on He migration (HeIRE)
 - work in progress





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Energy deposition by synchrotron-based X-rays is similar to tritium betas.



- Same average energy of 5-10 keV.
 - Power deposited by tritium betas is E*N(E)
- Energy is deposited uniformly throughout the film
- Only 10% of incident energy is absorbed,

X-ray exposures of ErH₂ films were done at the Advanced Light Source synchrotron (LBNL)

• Experimental Arrangement:



- Environment: Water vapor in flowing He.
 - Eliminated ozone produced by X-rays in air.



Sample Cell on Scanner Cooling Block



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We exposed a stripe across the samples.







#108K 1.3 hr .17 Torr, 0.8% RH 120 ma-hr

#170K 1.5 hr 10 Torr, 48% RH 120 ma-hr

#168K 7.5 hr 9.5 Torr, 45% RH 680 ma-hr



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X-ray exposures in H₂O vapor increased the oxide thickness, similar to betas.



- Nascent-H pickup is expected to be too small to discern by thermodesorption.
- Plans (delayed by funding):
 - Use D_2O
 - Expose larger ErH₂ area

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- Quantify nascent-D by NRA or TDS

Hydrogen pickup can be deduced *in-situ* from the change in electrical resistivity of the film.



Near-surface He diffusion and trapping parameters are measured by Implant/Re-emission.



Experiments with ErH₂ films show lower diffusivity and significant He trapping at RT.

- He diffusion through Er₂O₃ is assumed rapid.
- Early time dependence is approximated by draining of slab (L=He⁺ range, SRIM):

 $p(He) \approx [4Dt/\pi L^2]^{1/2}$

• The re-emission fraction indicates lots of low-energy traps:

T(°C)	release/implant
27	.018
100	.06
150	.17
200	.38



The cause of low early He release from Er tritide films remains a mystery.

• Films appear to possess a "hydride phase" layer with significant He trapping.



- The beta-enhanced surface chemistry of tritides can be simulated using synchrotron X-rays on hydrides. -- We have observed oxide growth.
- Effects on He migration can be examined by implant/re-emission techniques.